

# ECG<sup>®</sup> Semiconductors

## ECG924, ECG924M

### Voltage Follower Operational Amplifier

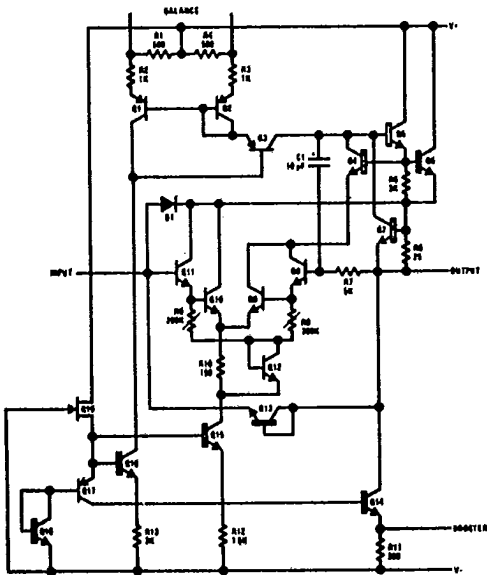
**Features**

- Input current: 10nA max. over temperature range
- Small signal bandwidth: 20MHz
- Slew rate: 30V/μs
- Supply voltage range: ±5V to ±18V

ECG924 and ECG924M are monolithic operational amplifiers internally connected as unity-gain non-inverting amplifiers. They use super-gain transistors in the input stage to get low bias current without sacrificing speed. In voltage follower applications, these devices have internal frequency compensation and provision for offset balancing.

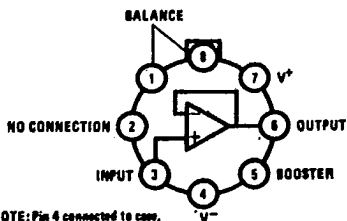
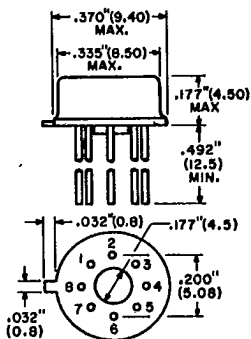
They are useful in fast sample and hold circuits, active filters, or as general-purpose buffers. Further, the frequency response is enough better than standard IC amplifiers that the followers can be included in the feedback loop without introducing instability.

**Schematic Diagram (Each Amplifier)**



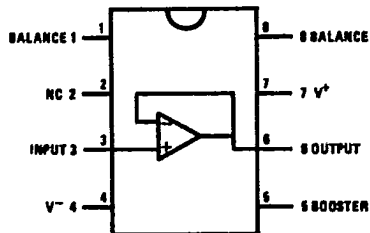
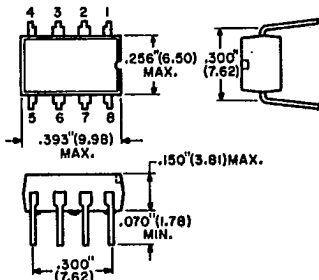
ECG924, ECG924M

**ECG924**



TOP VIEW

**ECG924M**



TOP VIEW

**Absolute Maximum Ratings**

Supply Voltage, $V_S$ .....	$\pm 18V$
Power Dissipation (Note 1), $P_D$ .....	500mW
Input Voltage (Note 2), $V_I$ .....	$\pm 15V$
Output Short Circuit Duration (Note 3), $t_s$ .....	Indefinite
Operating Temperature Range, $T_{opg}$ .....	$0^\circ C$ to $+70^\circ C$
Storage Temperature Range, $T_{stg}$ .....	$-65^\circ C$ to $+150^\circ C$
Lead Temperature (Soldering, 10 seconds) .....	$300^\circ C$
Junction Temperature, $T_j$ .....	$85^\circ C$

**Electrical Characteristics (Note 4)**

Characteristic	Symbol	Test Condition	Min	Typ	Max	Unit
Input Offset Voltage	$V_{IO}$	$T_A = 25^\circ C$		2.5	7.5	mV
Input Bias Current	$I_{IO}$	$T_A = 25^\circ C$		2.0	7.0	nA
Input Resistance	$R_I$	$T_A = 25^\circ C$	$10^{10}$	$10^{12}$		$\Omega$
Input Capacitance	$F_I$			1.5		pF
Large Signal Voltage Gain	$V_G$	$T_A = 25^\circ C,$ $V_S = \pm 15V,$ $V_{OUT} = \pm 10V,$ $R_L = 8k\Omega$	0.999	0.9999		V/V
Output Resistance	$R_O$	$T_A = 25^\circ C$		0.75	2.5	$\Omega$
Supply Current	$I_S$	$T_A = 25^\circ C$		3.9	5.5	mA
Input Offset Voltage	$V_{IO}$				10	mV
Temperature Drift		$0^\circ C \leq T_A \leq +70^\circ C$		10		$\mu V/^\circ C$
Input Bias Current	$I_B$				10	nA
Large Signal Voltage Gain	$V_G$	$V_S = \pm 15V,$ $V_{OUT} = \pm 10V,$ $R_L = 10k\Omega$	0.999			V/V
Output Voltage Swing (Note 5)	$V_{or}$	$V_S = \pm 15V,$ $R_L = 10k\Omega$	$\pm 10$			V
Supply Voltage Rejection Ratio	$V_{srr}$	$\pm 5V \leq V_S \leq \pm 18V$	70	80		dB

**Note 1:** For operating at elevated temperatures, devices in the TO-5 package must be derated based on a thermal resistance of  $150^\circ C/W$ , junction to ambient, or  $45^\circ C/W$ , junction to case. The thermal resistance of the dual-in-line package is  $100^\circ C/W$ , junction to ambient.

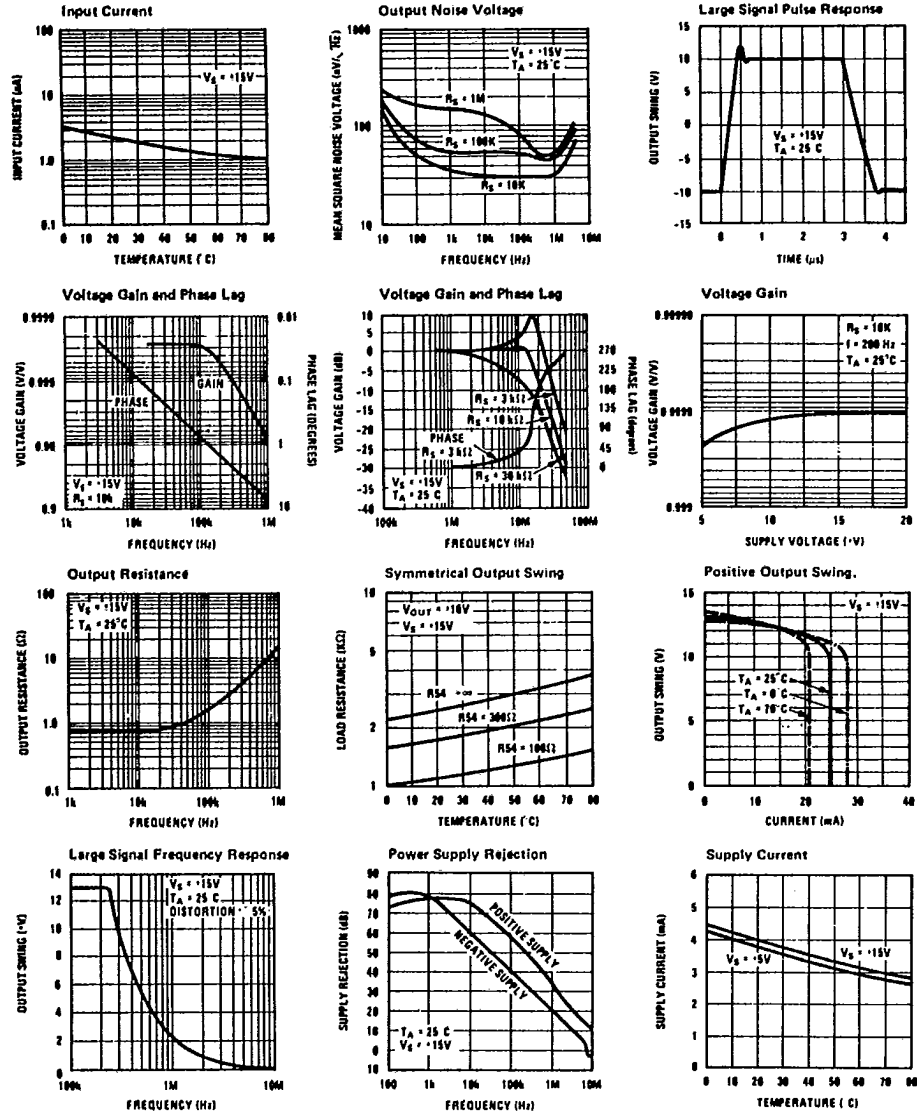
**Note 2:** For supply voltages less than  $\pm 15V$ , the absolute maximum input voltage is equal to the supply voltage.

**Note 3:** Continuous short circuit is allowed for  $70^\circ C$  case temperature or  $55^\circ C$  ambient temperature. It is necessary to insert a resistor greater than  $2k\Omega$  in series with the input when the amplifier is driven from low impedance sources to prevent damage when the output is shorted.

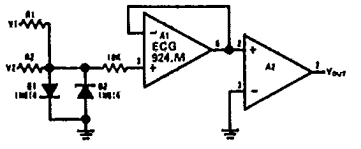
**Note 4:** These specifications apply -  $0^\circ C \leq T_A \leq 70^\circ C$ , unless otherwise specified.

**Note 5:** Increased output swing under load can be obtained by connecting an external resistor between the booster and  $V^-$  terminals. see curve.

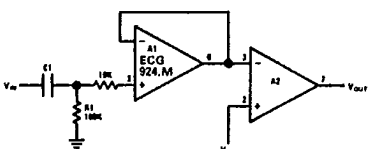
Typical Performance Characteristics



Typical Applications

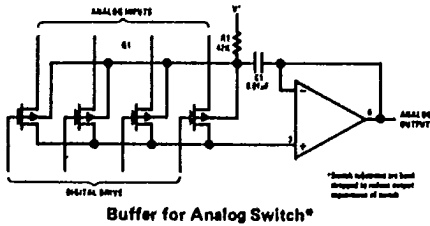


Comparator for Signals of Opposite Polarity

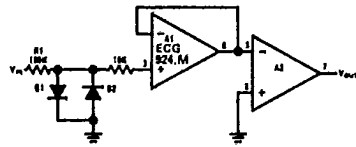


Comparator for AC Coupled Signals

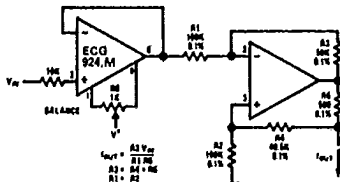
Typical Applications (Continued)



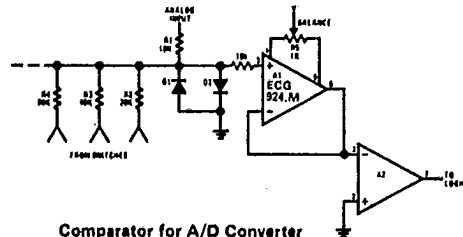
Buffer for Analog Switch\*



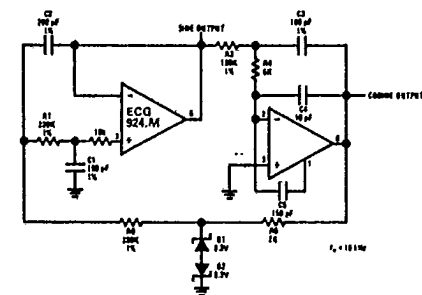
Zero Crossing Detector



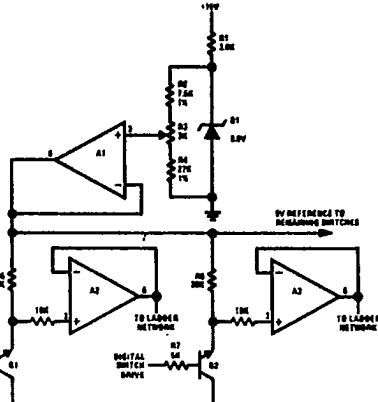
Bilateral Current Source



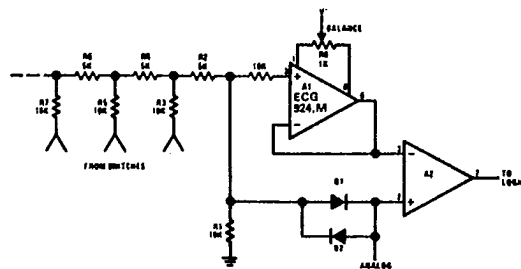
Comparator for A/D Converter Using a Binary-Weighted Network



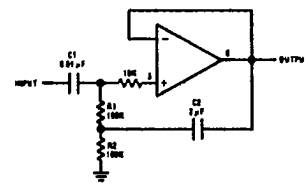
Sine Wave Oscillator



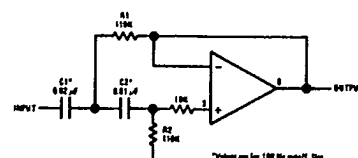
Driver for A/D Ladder Network



Comparator for A/D Converter Using a Ladder Network



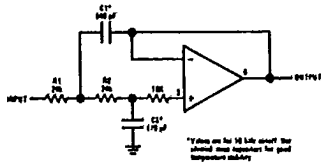
High Input Impedance AC Amplifier



High Pass Active Filter

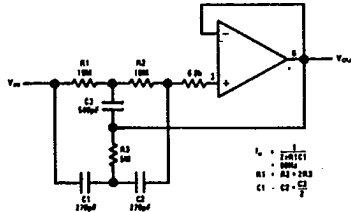
\*Values are for 100 Hz unless the standard performance equivalent for good component stability.

Typical Applications (Continued)



Low Pass Active Filter

\*Values are for 10 bit count for internal noise equivalent for good temperature stability

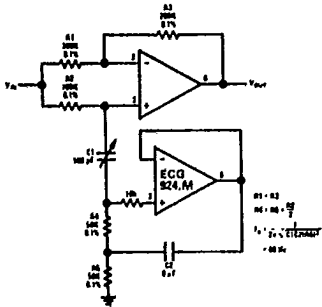


High Q Notch Filter

$$Q = \frac{1}{2\sqrt{R1R2}} \frac{C1 + C2}{C1C2}$$

$$R1 = R2 = 20k$$

$$C1 = C2 = 10\mu F$$

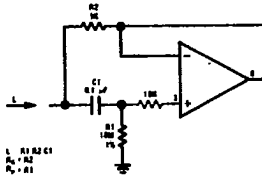


Tunable Notch Filter

$$R1 = R2$$

$$R3 = R4 = 10k$$

$$C1 = 10\mu F$$

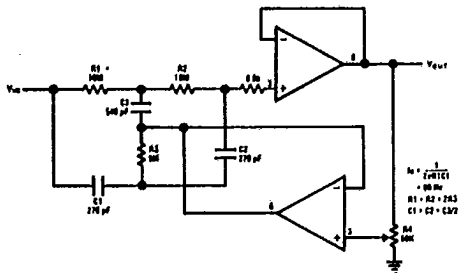


Simulated Inductor

$$L = R1C1$$

$$R1 = 10k$$

$$C1 = 10\mu F$$

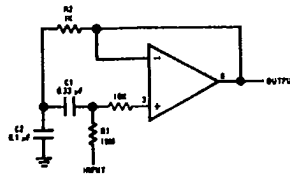


Adjustable Q Notch Filter

$$Q = \frac{1}{2\sqrt{R1R2}} \frac{C1 + C2}{C1C2}$$

$$R1 = R2 = 20k$$

$$C1 = C2 = 10\mu F$$

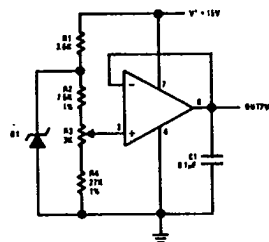


Bandpass Filter

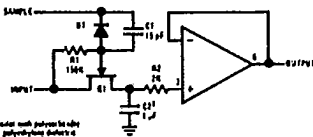
$$Q = \frac{1}{2\sqrt{R1R2}} \frac{C1 + C2}{C1C2}$$

$$R1 = R2 = 20k$$

$$C1 = C2 = 10\mu F$$

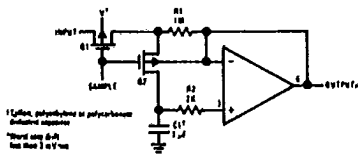


Buffered Reference Source



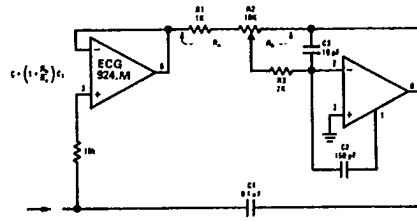
Sample and Hold

\*For operation with pulses to delay input or polyethylene substrate



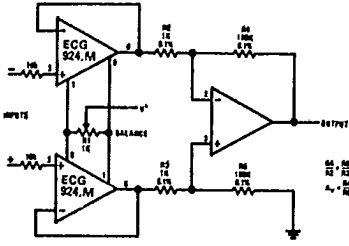
Low Drift Sample and Hold\*

\*Carbon, polyethylene or polyacrylonitrile substrate required

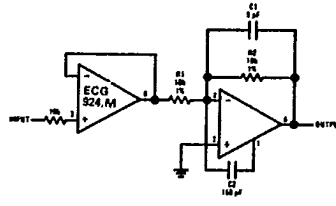


Variable Capacitance Multiplier

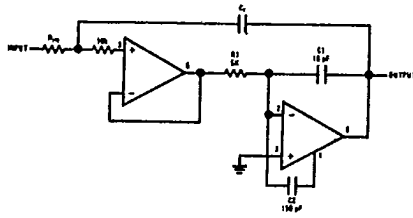
Typical Applications (Continued)



Differential Input Instrumentation Amplifier

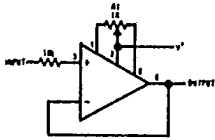


Fast Inverting Amplifier with High Input Impedance

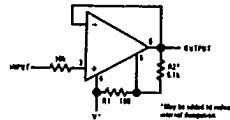


Fast Integrator with Low Input Current

Auxiliary Circuits



Offset Balancing Circuit



Increasing Negative Swing Under Load